

## DUAL OPERATIONAL AMPLIFIER—YD4558

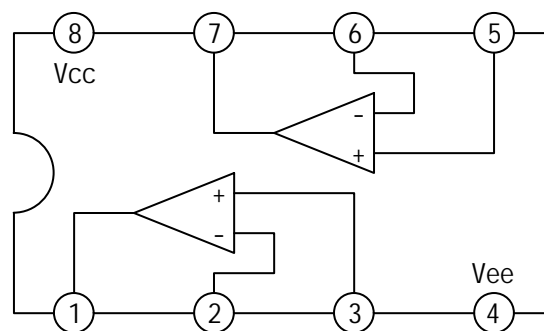
### DESCRIPTION

The YD4558 is a monolithic integrated circuit designed for dual operational amplifier.

### FEATURES

- \*NO frequency compensation required
- \*NO latch-up
- \*Large common mode and differential voltage range
- \*Parameter tracking cover temperature range
- \*Gain and phase match between amplifiers
- \*Internally frequency compensated
- \*Low noise input transistors ( $V_{in}=2.5 \mu V$ )

### BLOCK DIAGRAM



[www.DataSheet.in](http://www.DataSheet.in)

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**ABSOLUTE MAXIMUM RATINGS** (Tamb=25 )

PARAMETER		SYMBOL	VALUE	UNIT
Supply Voltage		V <sub>CC</sub>	± 18	V
Differential Input Voltage		V <sub>I(DIFF)</sub>	± 30	V
Power Dissipation	DIP8	P <sub>D</sub>	500	mW
	SOP8		250	
D terminal Output Voltage		V <sub>I</sub>	± 15	V
Operating Temperature		T <sub>opr</sub>	-20 ~ +75	
Storage Temperature		T <sub>stg</sub>	-40 ~ +125	

**ELECTRICAL CHARACTERISTICS**

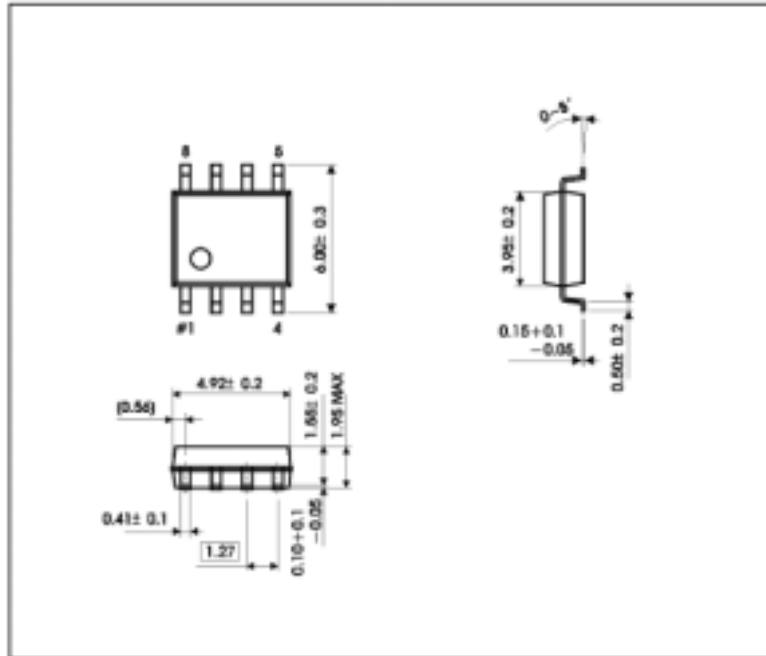
(V<sub>CC</sub>=15V, V<sub>EE</sub>=-15V, Tamb=25 , Unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Supply Current	I <sub>CC</sub>			4.0	6.0	mA
Input Offset Voltage	V <sub>IO</sub>	R <sub>s</sub> < 10k		0.5	6	mV
Input Offset Current	I <sub>IO</sub>			5	200	nA
Input Bias Current	I <sub>BIAS</sub>			25	500	nA
Large Signal Voltage Gain	A <sub>VO</sub>	V <sub>o(p-p)</sub> =10V, R <sub>L</sub> < 2k	86	100		dB
Common Mode Input Voltage Range	V <sub>ICM</sub>		± 12	± 14		V
Common Mode Rejection Ratio	K <sub>CMR</sub>	R <sub>s</sub> < 10k	70	90		dB
Supply Voltage Rejection Ratio	K <sub>SVR</sub>	R <sub>s</sub> < 10k	76.5	90		dB
Output Voltage Swing	V <sub>o(p-p)</sub>	R <sub>s</sub> > 10k		± 12	± 14	V
Slew Rate	SR	V <sub>i</sub> =20mV, R <sub>L</sub> > 2k , C <sub>L</sub> < 100p		1.0		V/μs
Rise Time	T <sub>RISE</sub>	V <sub>i</sub> =20mV, R <sub>L</sub> > 2k , C <sub>L</sub> < 100p		0.3		μs
Overshoot	OS	V <sub>i</sub> =20mV, R <sub>L</sub> > 2k , C <sub>L</sub> < 100p		15		%

OUTLINE DRAWING

SOP-8

unit:mm



DIP-8

unit:mm

